

2SK1579

Silicon N Channel MOS FET

REJ03G0956-0200

(Previous: ADE-208-1296)

Rev.2.00 Sep 07, 2005

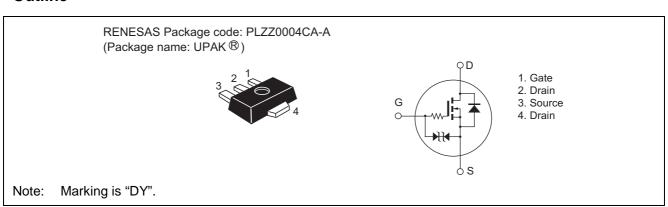
Application

High speed power switching

Features

- Low on-resistance
- High speed switching
- Suitable for low voltage operation

Outline



*UPAK is a trademark of Renesas Technology Corp.

Absolute Maximum Ratings

 $(Ta = 25^{\circ}C)$

Item	Symbol	Ratings	Unit
Drain to source voltage	V _{DSS}	12	V
Gate to source voltage	V _{GSS}	±7	V
Drain current	I _D	2	Α
Drain peak current	I _{D(pulse)} *1	4	Α
Body to drain diode reverse drain current	I _{DR}	2	Α
Channel power dissipation	Pch ^{*2}	1	W
Channel temperature	Tch	150	°C
Storage temperature	Tstg	-55 to +150	°C

Notes: 1. PW \leq 100 μ s, duty cycle \leq 10%

2. Value on the alumina ceramic board (12.5 \times 20 \times 0.7 mm)

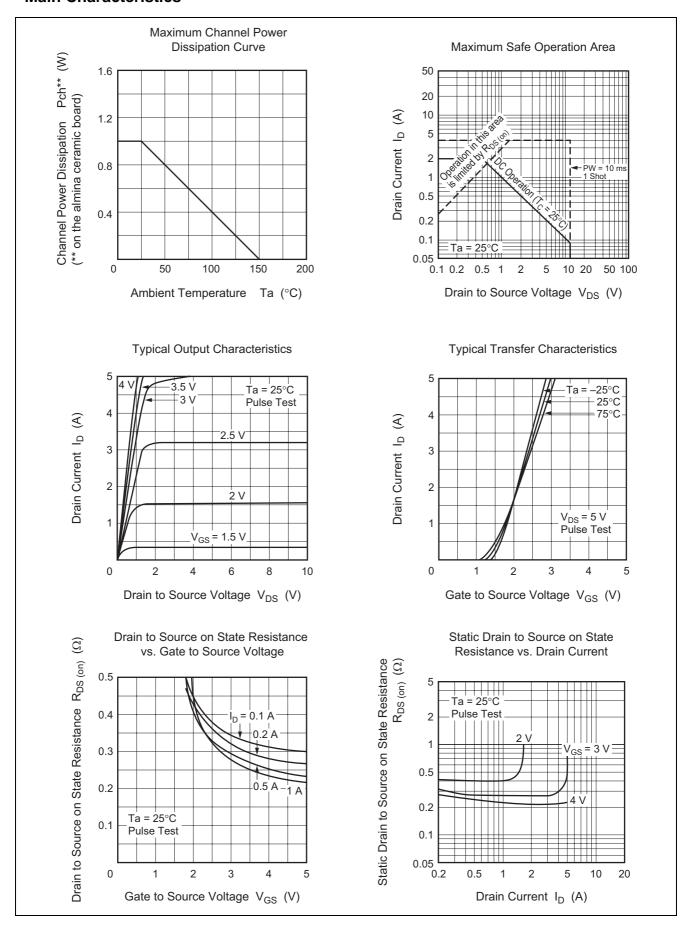
Electrical Characteristics

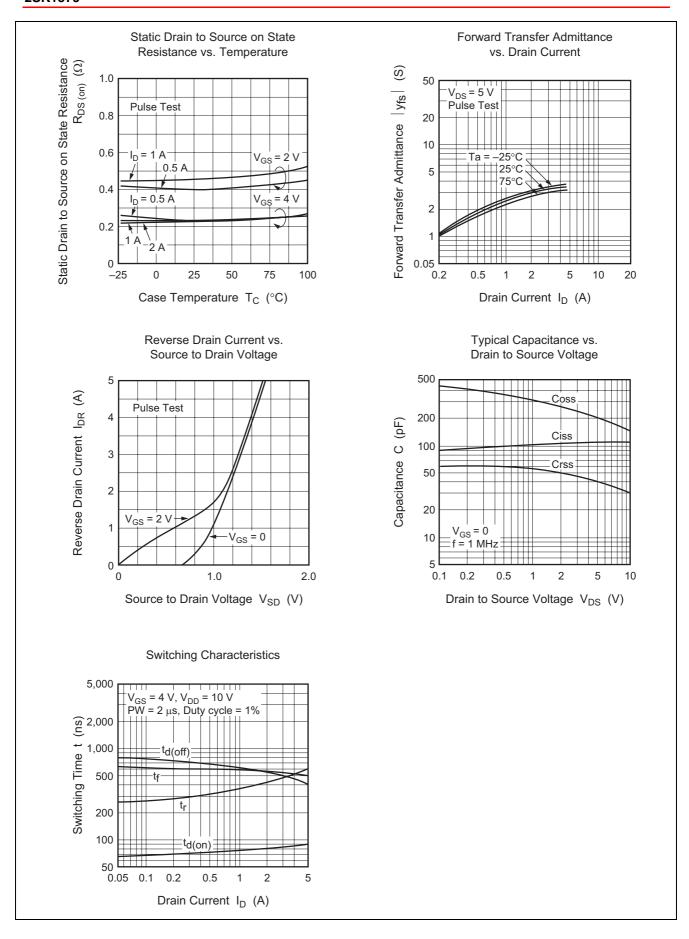
 $(Ta = 25^{\circ}C)$

Item	Symbol	Min	Тур	Max	Unit	Test conditions
Drain to source cutoff current	I _{DSS}	_	_	1	μΑ	$V_{DS} = 8 \text{ V}, V_{GS} = 0$
Gate to source cutoff current	I _{GSS}	-	_	±5	μΑ	$V_{GS} = \pm 6.5 \text{ V}, V_{DS} = 0$
Gate to source cutoff voltage	$V_{GS(off)}$	0.4	_	1.4	V	$V_{DS} = 5 \text{ V}, I_{D} = 100 \mu\text{A}$
Drain to source on resistance (1)	R _{DS(on)} 1	_	0.36	0.7	Ω	$V_{GS} = 2.2 \text{ V}, I_D = 0.5 \text{ A}^{*3}$
Drain to source on resistance (2)	R _{DS(on)} 2	_	0.25	0.35	Ω	$V_{GS} = 4 \text{ V}, I_D = 1 \text{ A}^{*3}$
DC forward transfer admittance	y _{fs}	1	2.5	_		$V_{DS} = 5 \text{ V}, I_{D} = 1 \text{ A},$
						$\Delta V_{GS} = 0.1 \text{ V}^{*3}$
Input capacitance	Ciss		110		pF	$V_{DS} = 5 V$, $V_{GS} = 0$,
Reverse transfer capacitance	Crss		30	_	pF	f = 1 MHz
Output capacitance	Coss	_	150	_	pF	
Turn-on time	t _(on)	_	500	_	ns	$I_D = 0.2 \text{ A}, V_{GS} = 0,$
Turn-off time	t _(off)	_	1500	_	ns	Vin = 4 V, $R_L = 51 \Omega^{*3}$

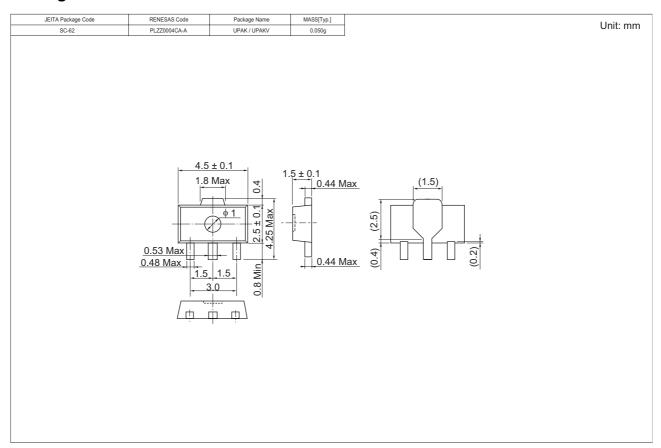
Note: 3. Pulse Test

Main Characteristics





Package Dimensions



Ordering Information

Part Name	Quantity	Shipping Container
2SK1579DY	3000 pcs	Taping, φ178 mm Reel

Note: For some grades, production may be terminated. Please contact the Renesas sales office to check the state of production before ordering the product.

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Renesas Technology Europe Limited
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Renesas Technology Singapore Pte. Ltd.

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Renesas Technology Korea Co., Ltd.Kukje Center Bldg. 18th Fl., 191, 2-ka, Hangang-ro, Yongsan-ku, Seoul 140-702, Korea Tel: <82> 2-796-3115, Fax: <82> 2-796-2145

Renesas Technology Malaysia Sdn. Bhd. Unit 906, Block B, Menara Amcorp, Amcorp Trade Centre, No.18, Jalan Persiaran Barat, 46050 Petaling Jaya, Selangor Darul Ehsan, Malaysia Tel: <603> 7955-9390, Fax: <603> 7955-9510

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